

# 7MBR10XKC120-50

IGBT Modules

**Power Module(X series)**  
1200V / 10A / PIM

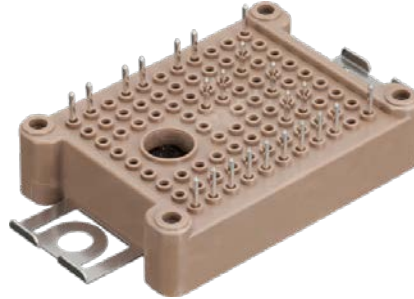
□ **Features**

- Low  $V_{CE(sat)}$
- Compact Package
- P.C.Board Mount Module
- Converter Diode Bridge Dynamic Brake Circuit
- RoHS compliant Product

□ **Applications**

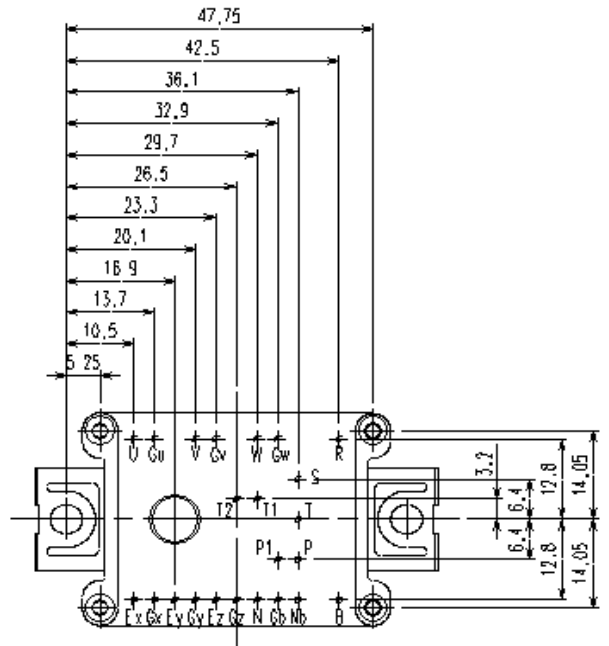
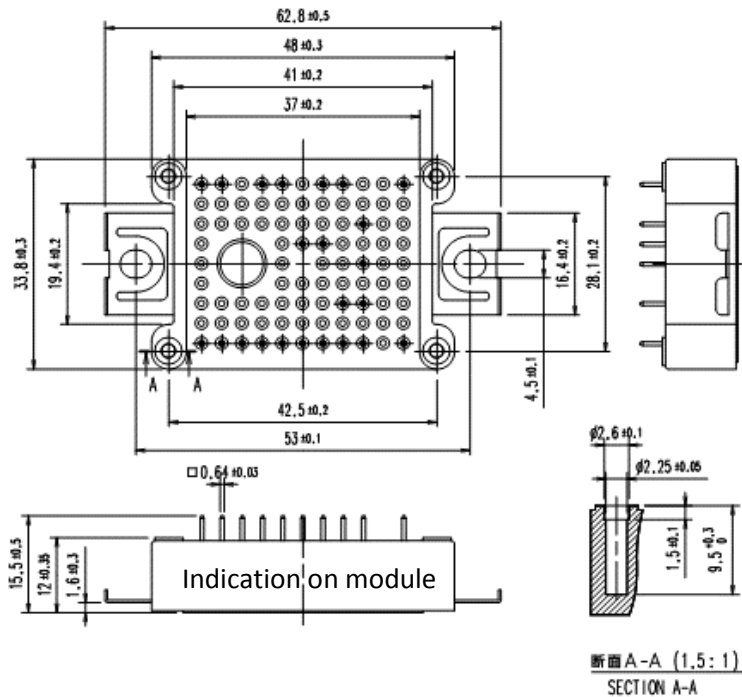
- Inverter for Motor Drive
- AC and DC Servo Drive Amplifier
- Uninterruptible Power Supply

□ **Typical appearance**



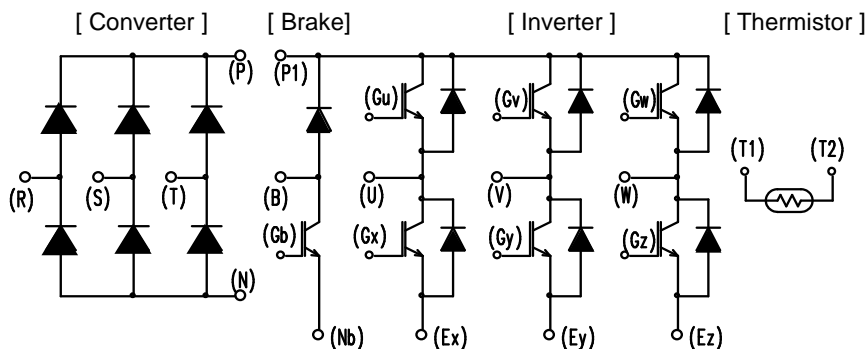
□ **Outline drawing ( Unit : mm )**

shows theoretical dimension.  
( ) shows reference dimension.



Weight: 25 g (typ.)  
PIN POSITIONS WITH TOLERANCE  $\pm 0.4$

□ **Equivalent circuit**



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□ Maximum ratings ( at  $T_c = 25^\circ\text{C}$  unless otherwise specified )

Items		Symbols	Conditions		Maximum ratings	Units	
Inverter	Collector-Emitter voltage	$V_{CES}$			1200	V	
	Gate-Emitter voltage	$V_{GES}$			$\pm 20$	V	
	Collector current	$I_C$	Continuous	$T_c=100^\circ\text{C}$	10	A	
		$I_C$ pulse	1ms		20		
	Forward current	$I_F$	Continuous		10		
		$I_F$ pulse	1ms		20		
Collector power dissipation	$P_C$	1 device		105	W		
Brake IGBT	Collector-Emitter voltage	$V_{CES}$			1200	V	
	Gate-Emitter voltage	$V_{GES}$			$\pm 20$	V	
	Collector current	$I_C$	Continuous	$T_c=100^\circ\text{C}$	10	A	
		$I_C$ pulse	1ms		20		
Collector power dissipation	$P_C$	1 device		105	W		
Brake FWD	Forward current	$I_F$	Continuous		10	A	
		$I_{FRM}$	1ms		20		
	Repetitive peak reverse voltage	$V_{RRM}$			1200	V	
Repetitive peak reverse voltage	$V_{RRM}$			1600	V		
Converter	Average output current	$I_O$	Three-phase full wave rectified	$T_c=80^\circ\text{C}$	10	A	
	Surge current (Non-Repetitive) (*1)	$I_{FSM}$	$t=10\text{ms}$ , Half sine wave form	$T_{vj}=25^\circ\text{C}$	350	A	
				$T_{vj}=150^\circ\text{C}$	300		
	$I^2t$ (Non-Repetitive) (*1)	$I^2t$		$T_{vj}=25^\circ\text{C}$	615	A <sup>2</sup> s	
$T_{vj}=150^\circ\text{C}$				450			
Junction temperature		$T_{vj}$	Inverter, Brake		175	°C	
			Converter		150		
Operating junction temperature (under switching conditions)		$T_{vjop}$	Inverter, Brake		175		
			Converter		150		
Case temperature		$T_c$			125		
Storage temperature		$T_{stg}$			-40 ~ 125		
Isolation voltage	between terminals and copper base (*2)	$V_{iso}$	A.C. : 1min.		2500		Vrms
	between thermistor and others (*3)						
Screw torque (*4)	Mounting	-	M4		1.7	N·m	

(\*1)  $T_{vj}$  : Temperature at test start.

(\*2) All terminals should be connected together during the test.

(\*3) Two thermistor terminals should be connected together, other terminals should be connected together and shorted to base plate during the test.

(\*4) Recommendable value : Mounting 1.3 ~ 1.7 N·m (M4)

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**IGBT Modules**

 □ Electrical characteristics ( at  $T_{vj} = 25^{\circ}\text{C}$  unless otherwise specified)

Items	Symbols	Conditions	Characteristics			Units	
			min.	typ.	max.		
Zero Gate voltage collector current	$I_{CES}$	$V_{GE} = 0\text{V}$ $V_{CE} = 1200\text{V}$	-	-	50	$\mu\text{A}$	
Gate-Emitter leakage current	$I_{GES}$	$V_{CE} = 0\text{V}$ $V_{GE} = +20/-20\text{V}$	-	-	100	nA	
Gate-Emitter threshold voltage	$V_{GE(th)}$	$V_{CE} = 20\text{V}$ $I_C = 10\text{mA}$	6.0	6.5	7.0	V	
Collector-Emitter saturation voltage	$V_{CE(sat)}$ (terminal)	$V_{GE} = 15\text{V}$ $I_C = 10\text{A}$	$T_{vj}=25^{\circ}\text{C}$	-	1.55	2.00	V
			$T_{vj}=25^{\circ}\text{C}$	-	1.50	1.95	
	$T_{vj}=125^{\circ}\text{C}$		-	1.85	-		
	$T_{vj}=150^{\circ}\text{C}$		-	1.95	-		
	$T_{vj}=175^{\circ}\text{C}$		-	2.00	-		
	$V_{CE(sat)}$ (chip)						
Internal Gate resistance	$r_g$	-	-	0	-	$\Omega$	
Capacitance	$C_{ies}$	$V_{CE} = 10\text{V}, V_{GE} = 0\text{V}, f = 1\text{MHz}$	-	1.1	-	nF	
	$C_{oes}$		-	0.04	-		
	$C_{res}$		-	0.01	-		
Gate charge	$Q_G$	$V_{CC} = 600\text{V}$ $V_{GE} = -15 \rightarrow +15\text{V}$ $I_C = 10\text{A}$	-	68	-	nC	
Forward voltage	$V_F$ (terminal)	$I_F = 10\text{A}$	$T_{vj}=25^{\circ}\text{C}$	-	1.95	2.40	V
	$V_F$ (chip)		$T_{vj}=25^{\circ}\text{C}$	-	1.90	2.35	
			$T_{vj}=125^{\circ}\text{C}$	-	1.95	-	
			$T_{vj}=150^{\circ}\text{C}$	-	1.90	-	
			$T_{vj}=175^{\circ}\text{C}$	-	1.85	-	
Switching time (*1)	$t_{d(on)}$	$V_{CC} = 600\text{V}$ $I_C, I_F = 10\text{A}$ $L_S = 30\text{nH}$ $V_{GE} = +15/-15\text{V}$ $R_G = 47\ \Omega$	$T_{vj}=25^{\circ}\text{C}$	-	0.05	-	$\mu\text{s}$
			$T_{vj}=125^{\circ}\text{C}$	-	0.05	-	
			$T_{vj}=150^{\circ}\text{C}$	-	0.05	-	
			$T_{vj}=175^{\circ}\text{C}$	-	0.05	-	
	$t_r$		$T_{vj}=25^{\circ}\text{C}$	-	0.03	-	
			$T_{vj}=125^{\circ}\text{C}$	-	0.03	-	
			$T_{vj}=150^{\circ}\text{C}$	-	0.03	-	
			$T_{vj}=175^{\circ}\text{C}$	-	0.03	-	
	$t_{d(off)}$		$T_{vj}=25^{\circ}\text{C}$	-	0.19	-	
			$T_{vj}=125^{\circ}\text{C}$	-	0.22	-	
			$T_{vj}=150^{\circ}\text{C}$	-	0.22	-	
			$T_{vj}=175^{\circ}\text{C}$	-	0.23	-	
	$t_f$		$T_{vj}=25^{\circ}\text{C}$	-	0.12	-	
			$T_{vj}=125^{\circ}\text{C}$	-	0.18	-	
			$T_{vj}=150^{\circ}\text{C}$	-	0.20	-	
			$T_{vj}=175^{\circ}\text{C}$	-	0.22	-	
Reverse recovery time	$t_{rr}$	$T_{vj}=25^{\circ}\text{C}$	-	0.06	-		
		$T_{vj}=125^{\circ}\text{C}$	-	0.09	-		
		$T_{vj}=150^{\circ}\text{C}$	-	0.15	-		
		$T_{vj}=175^{\circ}\text{C}$	-	0.20	-		

 (\*1) Turn on time ( $t_{on}$ ) =  $t_{d(on)} + t_r$ , Turn off time ( $t_{off}$ ) =  $t_{d(off)} + t_f$

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Items	Symbols	Conditions	Characteristics			Units	
			min.	typ.	max.		
Inverter Switching loss (per pulse)	$E_{on}$	$V_{CC} = 600V$ $I_C, I_F = 10A \quad L_s = 30nH$ $V_{GE} = +15/-15V$ $R_G = 47 \Omega$	$T_{vj}=25^\circ C$	-	0.72	-	mJ
			$T_{vj}=125^\circ C$	-	0.96	-	
			$T_{vj}=150^\circ C$	-	1.06	-	
			$T_{vj}=175^\circ C$	-	1.15	-	
	$E_{off}$	$V_{CC} = 600V$ $I_C, I_F = 10A \quad L_s = 30nH$ $V_{GE} = +15/-15V$ $R_G = 47 \Omega$	$T_{vj}=25^\circ C$	-	0.76	-	
			$T_{vj}=125^\circ C$	-	0.98	-	
			$T_{vj}=150^\circ C$	-	1.03	-	
			$T_{vj}=175^\circ C$	-	1.08	-	
	$E_{rr}$	$V_{CC} = 600V$ $I_C, I_F = 10A \quad L_s = 30nH$ $V_{GE} = +15/-15V$ $R_G = 47 \Omega$	$T_{vj}=25^\circ C$	-	0.51	-	
			$T_{vj}=125^\circ C$	-	0.72	-	
			$T_{vj}=150^\circ C$	-	0.85	-	
			$T_{vj}=175^\circ C$	-	0.97	-	
Zero Gate voltage collector current	$I_{CES}$	$V_{GE} = 0V$ $V_{CE} = 1200V$	-	-	50	$\mu A$	
Gate-Emitter leakage current	$I_{GES}$	$V_{CE} = 0V, \quad V_{GE} = +20/-20V$	-	-	100	nA	
Collector-Emitter saturation voltage	$V_{CE(sat)}$ (terminal)	$V_{GE} = 15V$ $I_C = 10A$	$T_{vj}=25^\circ C$	-	1.55	2.00	V
			$T_{vj}=25^\circ C$	-	1.50	1.95	
	$V_{CE(sat)}$ (chip)		$T_{vj}=125^\circ C$	-	1.85	-	
			$T_{vj}=150^\circ C$	-	1.95	-	
Internal Gate resistance	$r_g$	-	$T_{vj}=25^\circ C$	-	0	-	$\Omega$
			$T_{vj}=125^\circ C$	-	0	-	
			$T_{vj}=150^\circ C$	-	0	-	
			$T_{vj}=175^\circ C$	-	0	-	
Brake Switching time (*1)	$t_{d(on)}$	$V_{CC} = 600V$ $I_C = 10A \quad L_s = 30nH$ $V_{GE} = +15/-15V$ $R_G = 47 \Omega$	$T_{vj}=25^\circ C$	-	0.05	-	$\mu s$
			$T_{vj}=125^\circ C$	-	0.05	-	
			$T_{vj}=150^\circ C$	-	0.05	-	
			$T_{vj}=175^\circ C$	-	0.05	-	
	$t_r$	$V_{CC} = 600V$ $I_C = 10A \quad L_s = 30nH$ $V_{GE} = +15/-15V$ $R_G = 47 \Omega$	$T_{vj}=25^\circ C$	-	0.03	-	
			$T_{vj}=125^\circ C$	-	0.03	-	
			$T_{vj}=150^\circ C$	-	0.03	-	
			$T_{vj}=175^\circ C$	-	0.03	-	
	$t_{d(off)}$	$V_{CC} = 600V$ $I_C = 10A \quad L_s = 30nH$ $V_{GE} = +15/-15V$ $R_G = 47 \Omega$	$T_{vj}=25^\circ C$	-	0.19	-	
			$T_{vj}=125^\circ C$	-	0.22	-	
			$T_{vj}=150^\circ C$	-	0.22	-	
			$T_{vj}=175^\circ C$	-	0.23	-	
	$t_f$	$V_{CC} = 600V$ $I_C = 10A \quad L_s = 30nH$ $V_{GE} = +15/-15V$ $R_G = 47 \Omega$	$T_{vj}=25^\circ C$	-	0.12	-	
			$T_{vj}=125^\circ C$	-	0.18	-	
			$T_{vj}=150^\circ C$	-	0.20	-	
			$T_{vj}=175^\circ C$	-	0.22	-	
Reverse current	$I_{RRM}$	$V_R = 1200V$	-	-	50	$\mu A$	
Forward voltage	$V_F$ (terminal)	$I_F = 10A$	$T_{vj}=25^\circ C$	-	1.95	2.40	V
			$T_{vj}=25^\circ C$	-	1.90	2.35	
	$V_F$ (chip)		$T_{vj}=125^\circ C$	-	1.95	-	
			$T_{vj}=150^\circ C$	-	1.90	-	
Reverse current	$I_{RRM}$	$V_R = 1600V$	$T_{vj}=25^\circ C$	-	-	50	$\mu A$
			$T_{vj}=125^\circ C$	-	-	-	
			$T_{vj}=150^\circ C$	-	-	-	
			$T_{vj}=175^\circ C$	-	-	-	
Forward voltage	$V_{FM}$	$I_F = 10A$	terminal	-	1.00	1.45	V
			chip	-	0.95	1.40	
Resistance	$R$	$T = 25^\circ C$	-	5000	-	$\Omega$	
		$T = 100^\circ C$	465	495	520		
B value	$B$	$T = 25/50^\circ C$	3305	3375	3450	K	

(\*1) Turn on time ( $t_{on}$ ) =  $t_{d(on)} + t_r$ , Turn off time ( $t_{off}$ ) =  $t_{d(off)} + t_f$

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**NOTICE:**

The external gate resistance ( $R_G$ ) shown above is one of our recommended value for the purpose of minimum switching loss. However the optimum  $R_G$  depends on circuit configuration and/or environment. We recommend that the  $R_G$  has to be carefully chosen based on consideration if IGBT module matches design criteria, for example, switching loss, EMC/EMI, spike voltage, surge current and no unexpected oscillation and so on.

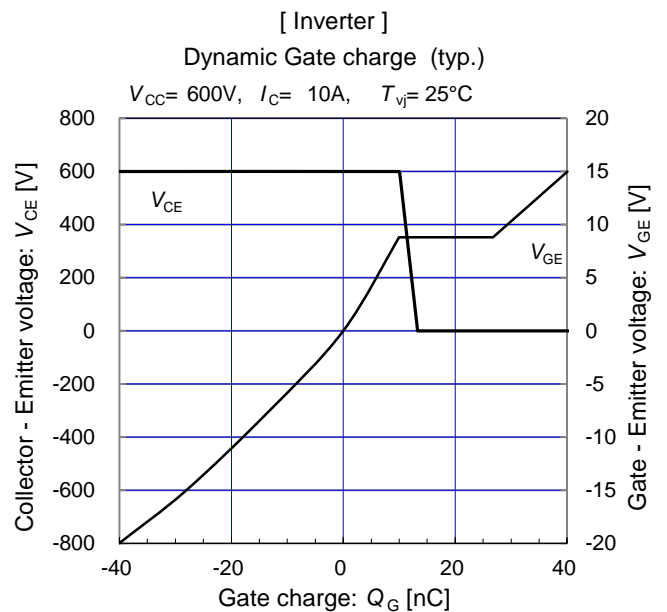
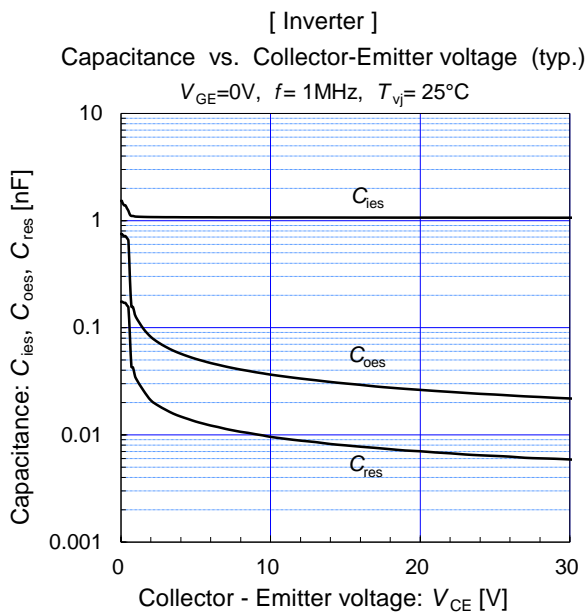
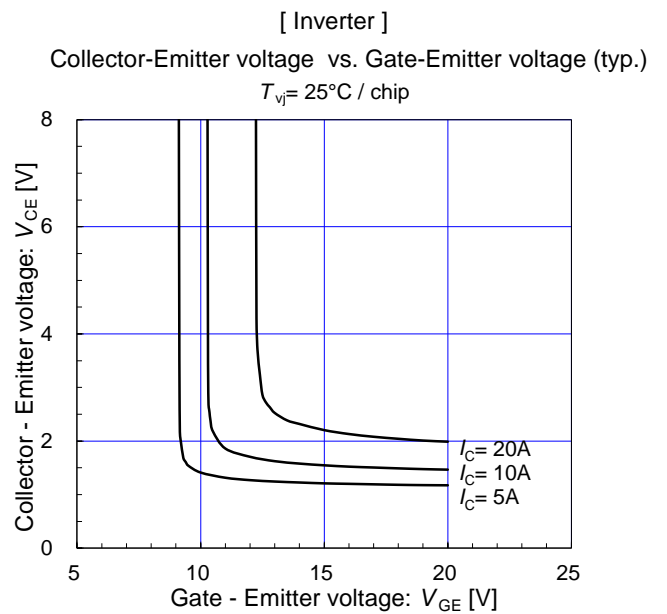
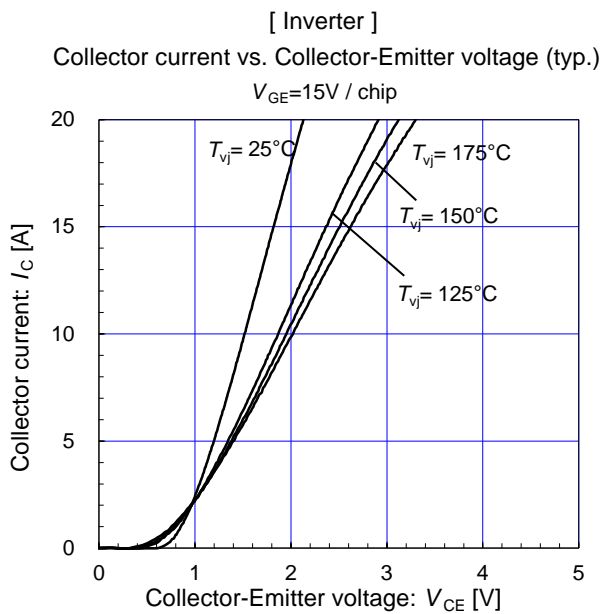
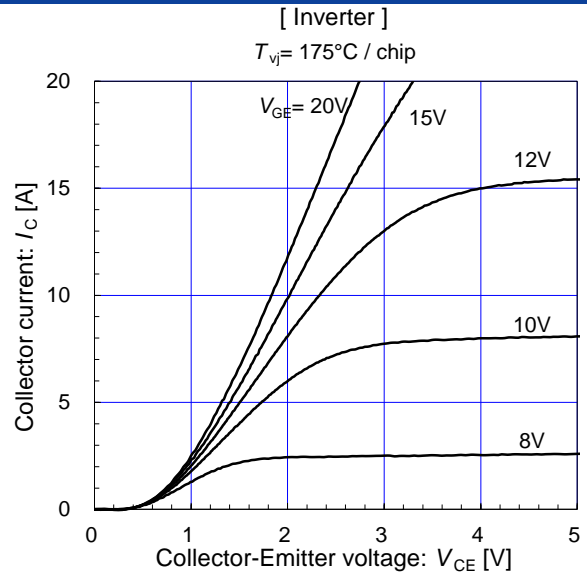
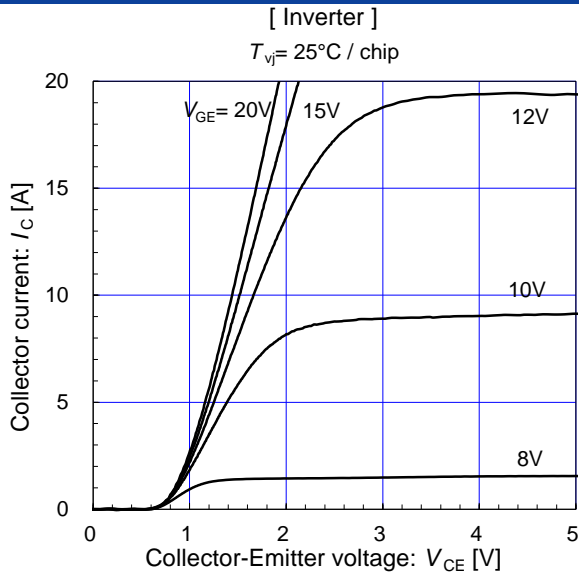
**□Thermal resistance characteristics**

Items	Symbols	Conditions	Characteristics			Units
			min.	typ.	max.	
Thermal resistance (1device)	$R_{th(j-c)}$	Inverter IGBT	-	-	1.40	°C/W
		Inverter FWD	-	-	1.75	
		Brake IGBT	-	-	1.40	
		Brake FWD	-	-	1.75	
		Converter Diode	-	-	0.97	
Contact thermal resistance(*1) (1device)	$R_{th(c-f)}$	Inverter IGBT	-	0.79	-	
		Inverter FWD	-	0.92	-	
		Brake IGBT	-	0.82	-	
		Brake FWD	-	0.76	-	
		Converter Diode	-	0.78	-	

(\*1) This is the value which is defined mounting on the additional cooling fin with 1W/(m·K) thermal grease.

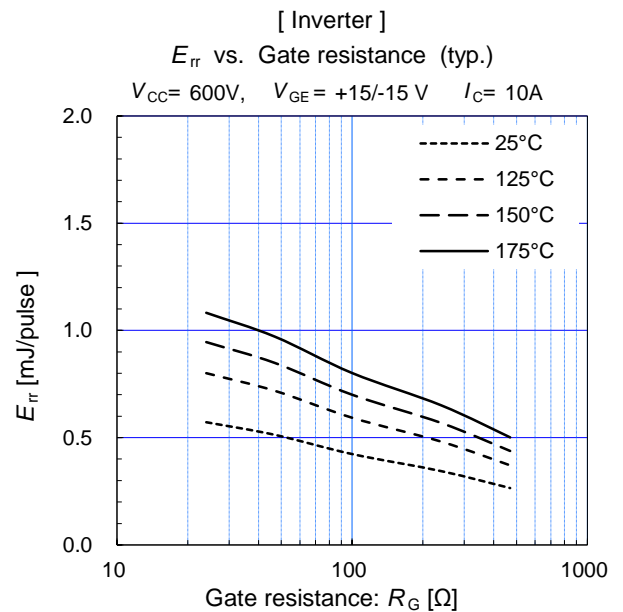
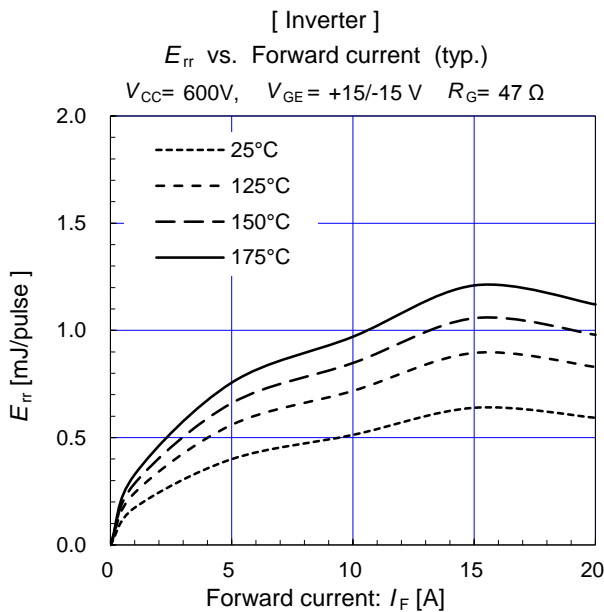
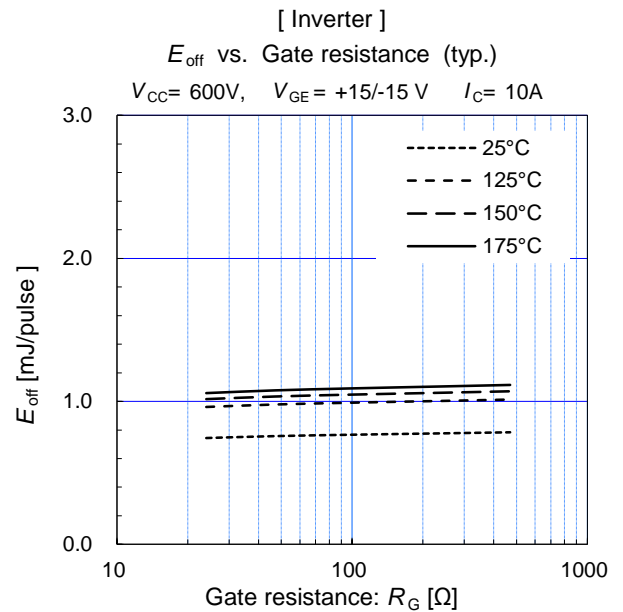
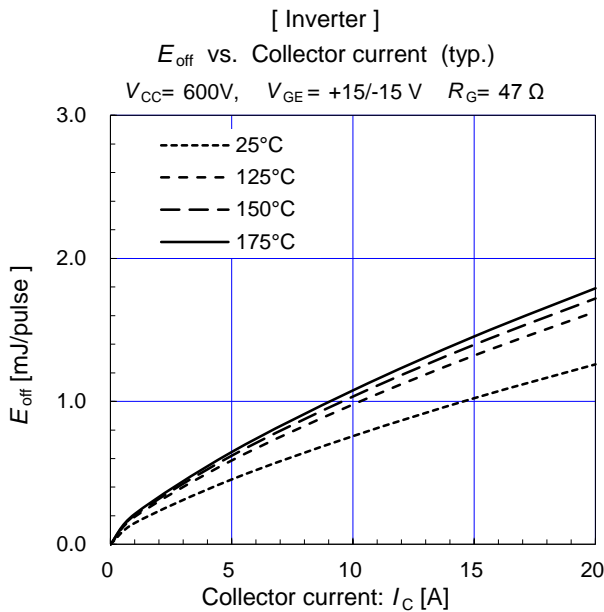
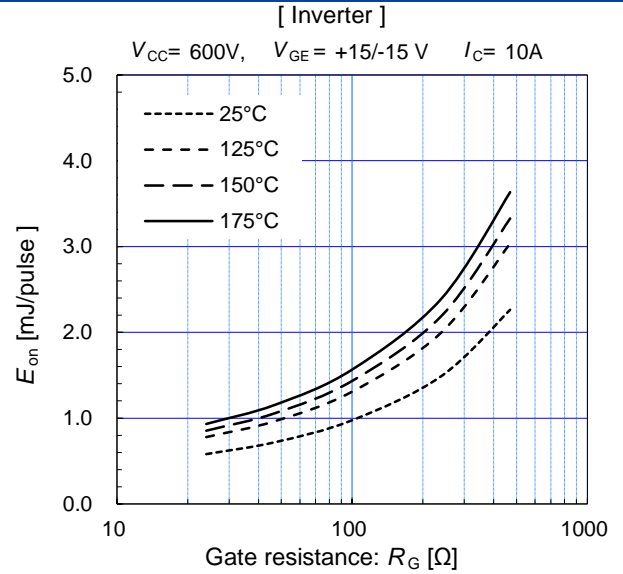
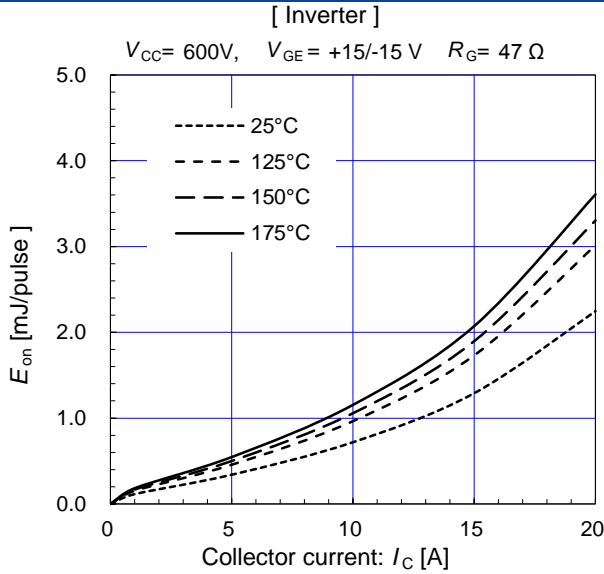
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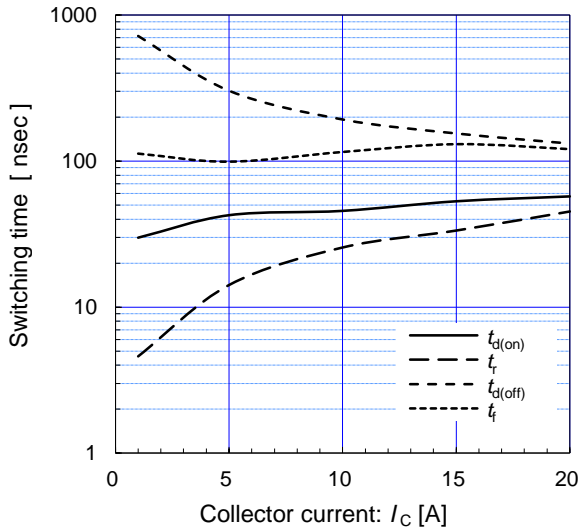


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IGBT Modules

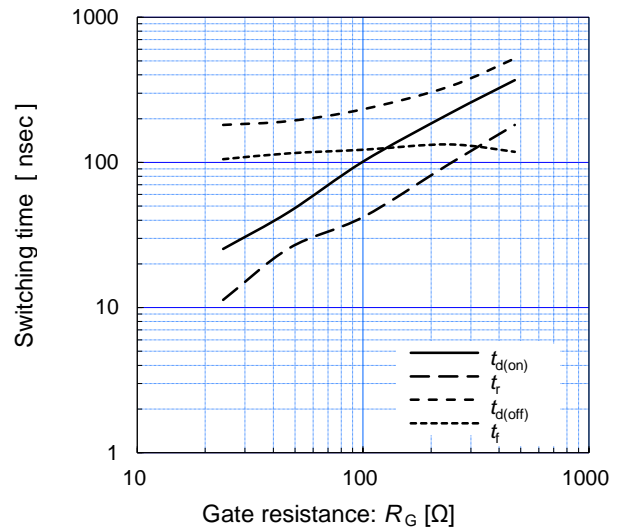
[ Inverter ]

$V_{CC}= 600V, R_G= 47\Omega \quad V_{GE}= +15/-15 V, T_{vj}= 25^\circ C$



[ Inverter ]

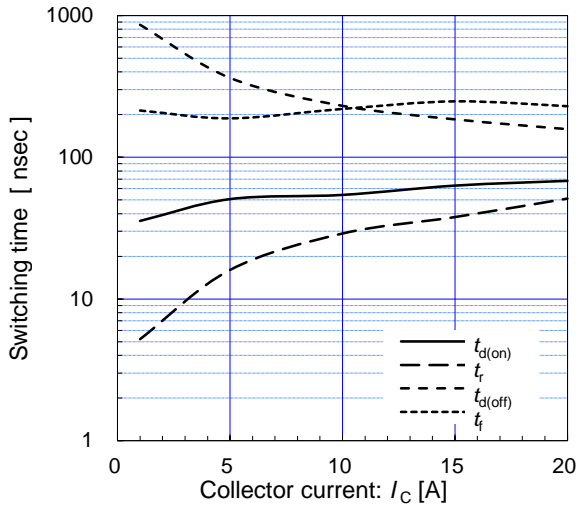
$V_{CC}= 600V, I_C= 10A, V_{GE}= +15/-15 V, T_{vj}= 25^\circ C$



[ Inverter ]

Switching time vs. Collector current (typ.)

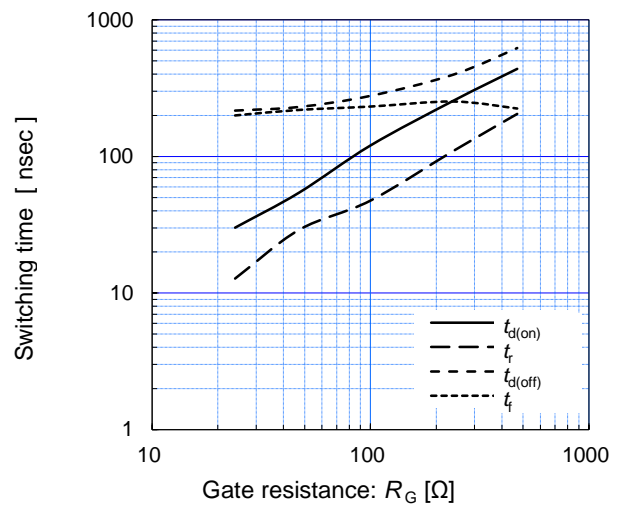
$V_{CC}= 600V, R_G= 47\Omega \quad V_{GE}= +15/-15 V, T_{vj}= 175^\circ C$



[ Inverter ]

Switching time vs. Gate resistance (typ.)

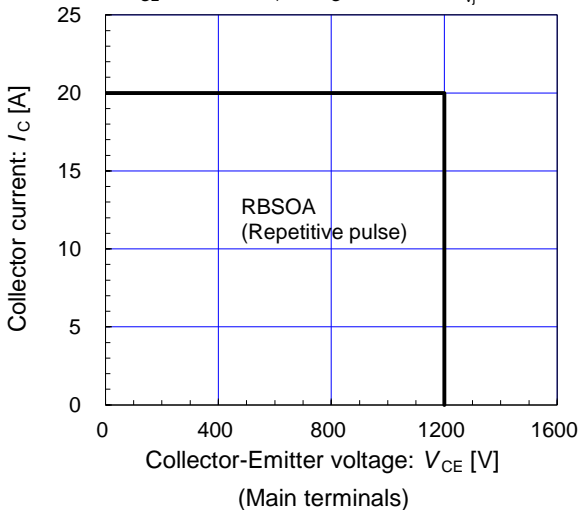
$V_{CC}= 600V, I_C= 10A, V_{GE}= +15/-15 V, T_{vj}= 175^\circ C$



[ Inverter ]

Reverse bias safe operating area (max.)

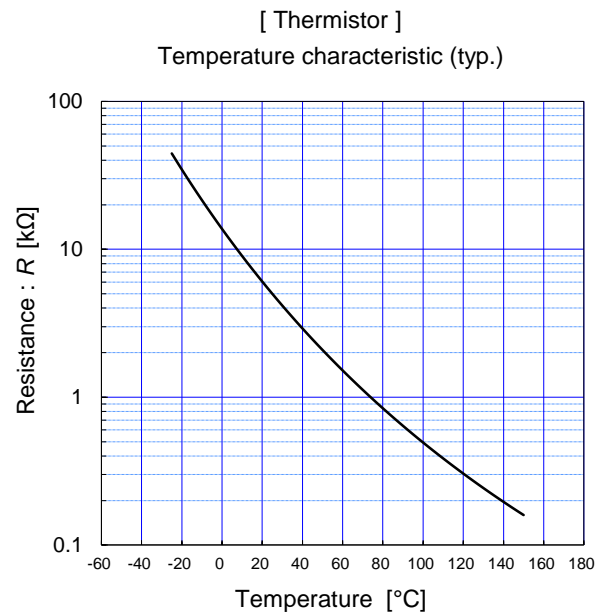
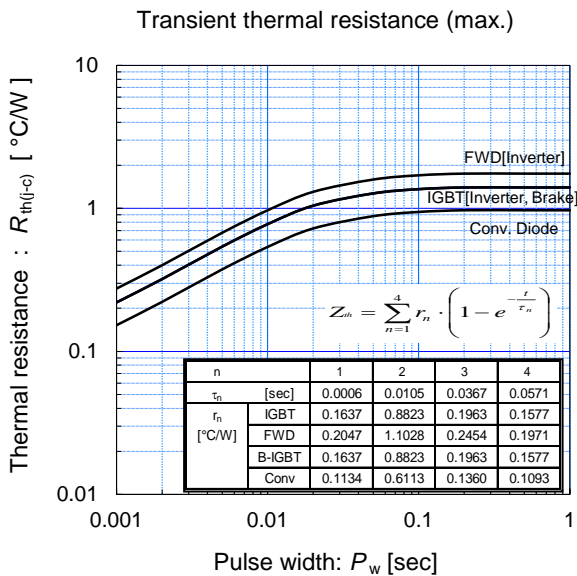
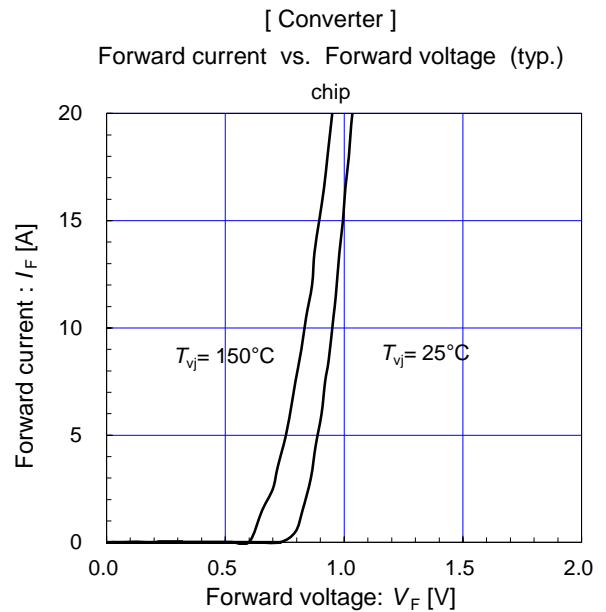
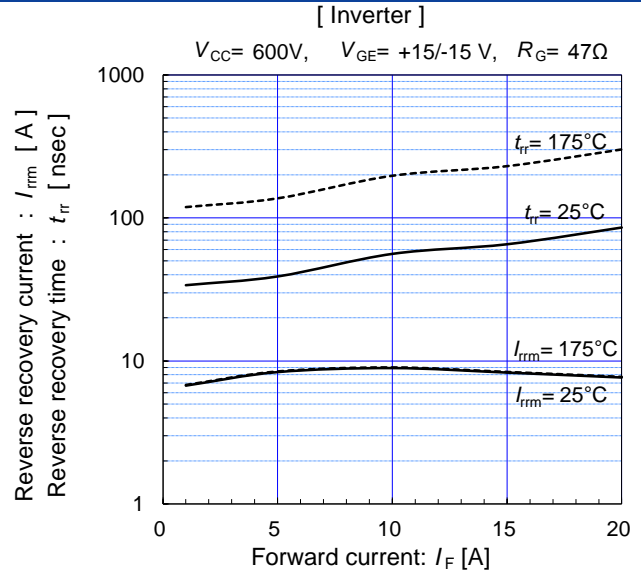
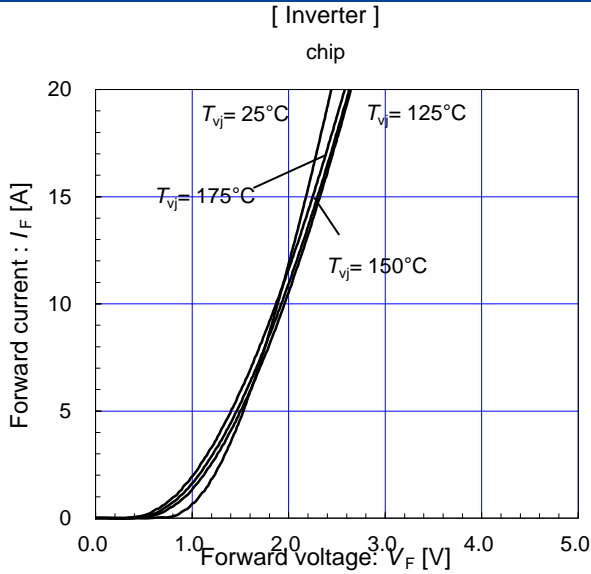
$V_{GE}= +15/-15 V, R_G \geq 47\Omega \quad T_{vj}= 175^\circ C$



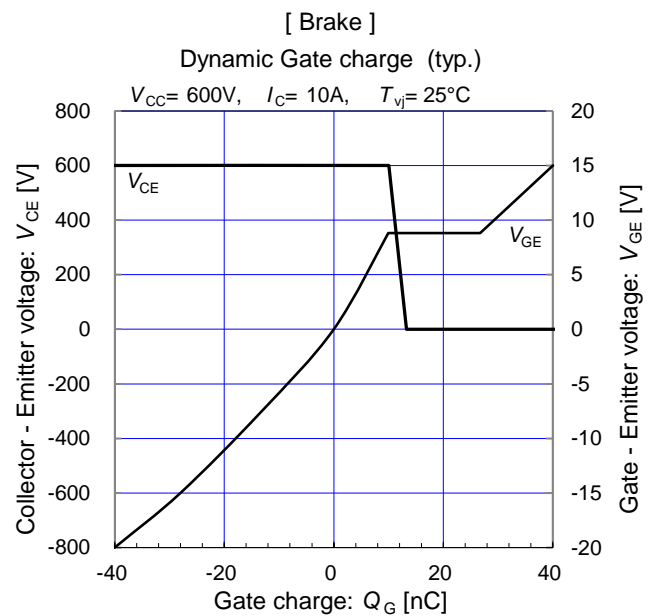
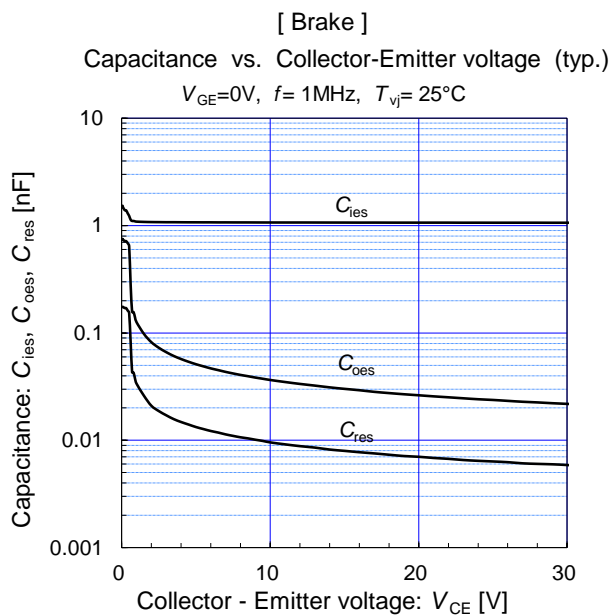
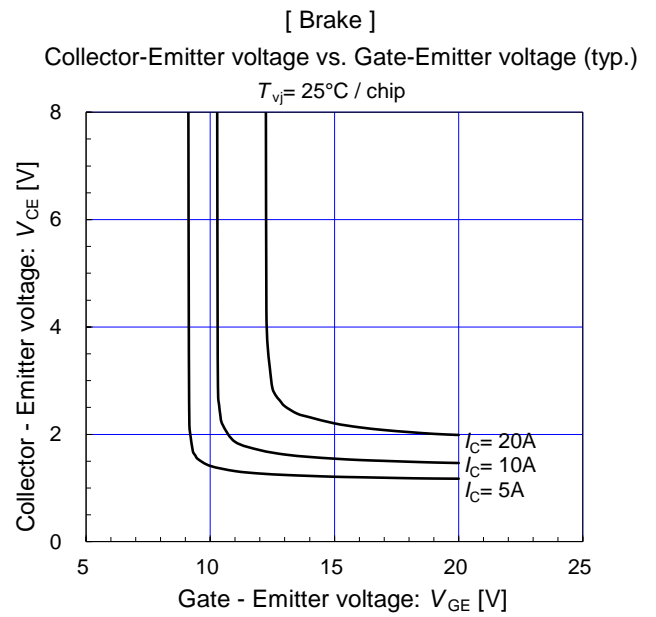
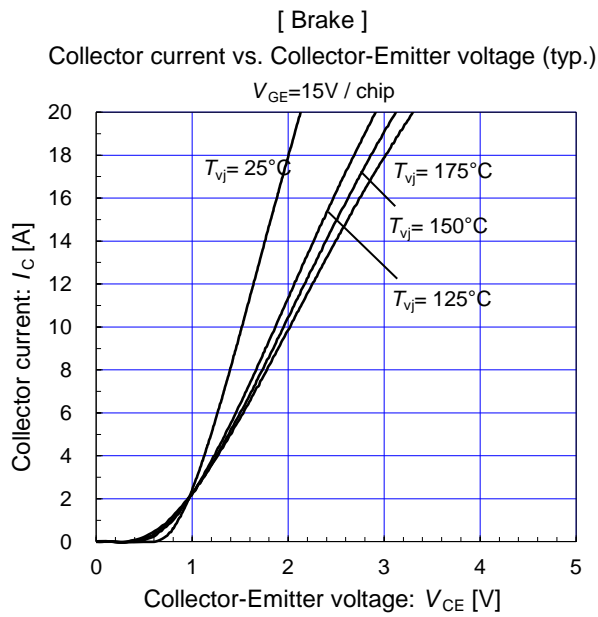
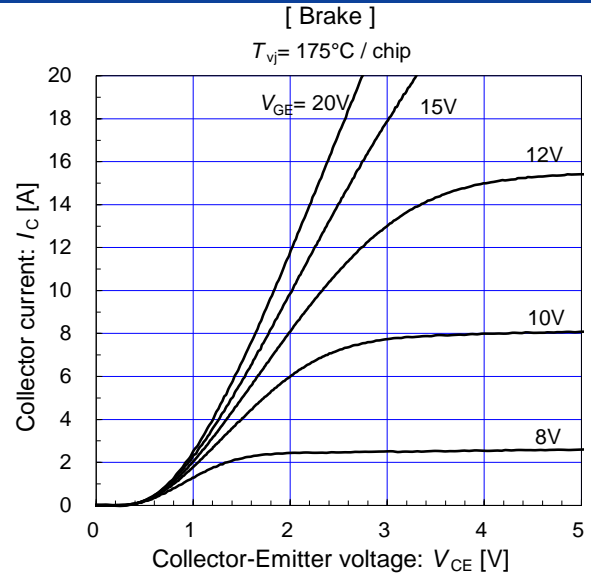
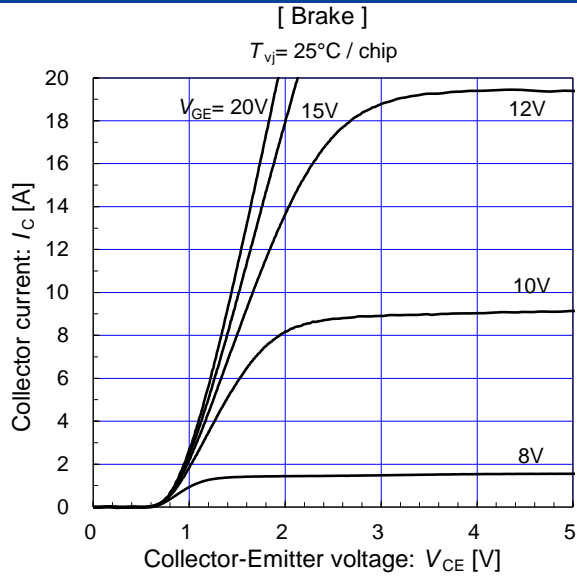


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## Warnings

1. This Catalog contains the product specifications, characteristics, data, materials, and structures as of 2/2018. The contents are subject to change without notice for specification changes or other reasons. When using a product listed in this Catalog, be sure to obtain the latest specifications.
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## IGBT Modules

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